
Phonon linewidth due to electron-phonon interactions with strong forward scattering in FeSe thin films on oxide substrates

Yan Wang,1 Louk Rademaker,2 Elbio Dagotto,1,3 and Steven Johnston1

1Department of Physics and Astronomy, University of Tennessee, Knoxville, Tennessee 37996, USA
2Kavli Institute for Theoretical Physics, University of California Santa Barbara, California 93106, USA
3Materials Science and Technology Division, Oak Ridge National Laboratory, Oak Ridge, Tennessee 37831, USA

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The discovery of an enhanced superconducting transition temperature $T_c$, in monolayers of FeSe grown on several oxide substrates has opened a different route to high-$T_c$ superconductivity through interface engineering. One proposal for the origin of the observed enhancement is an electron-phonon ($e$-$ph$) interaction across the interface that is peaked at small momentum transfers. In this paper, we examine the implications of such a coupling on the phononic properties of the system. We show that a strong forward scattering leads to a sizable broadening of phonon line shape, which may result in charge instabilities at long wavelengths. However, we further find that the inclusion of Coulombic screening significantly reduces the phonon broadening. Our results show that one might not expect anomalously broad phonon linewidths in the FeSe interface systems, despite the fact that the $e$-$ph$ interaction has a strong peak in the forward-scattering (small $q$) direction.

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I. INTRODUCTION

Due to its structural simplicity, FeSe has played a leading role in many experimental and theoretical studies on Fe-based superconductors since its discovery in 2008 [1]. The enduring interest in this compound is partially owed to the high $T_c$ (ranging between 55 and 100 K) achieved when monolayer FeSe films are grown on SrTiO$_3$ substrates [2,3] (FeSe/STO), a tenfold enhancement from the $T_c ∼ 8$ K of bulk FeSe crystals at ambient pressure [1]. Intriguingly, the high $T_c$ in the interfaced system proves to be robust for various oxide substrates, including SrTiO$_3$ (001) [2,4], BaTiO$_3$ (001) [5], SrTiO$_3$ (110) [6–8], anatase TiO$_2$ (001) [9], and rutile TiO$_2$ (100) [10]. These oxide substrates, terminated at the TiO$_2$ surface when interfaced with FeSe, have lattice parameters significantly larger than that of bulk FeSe and thus apply strong tensile strain on FeSe thin films. The anatase and rutile TiO$_2$ substrates even induce rather different strains along $a$ and $b$ axes of the monolayer FeSe. The $T_c$’s, however, are consistently above 55 K, as measured by angle-resolved photoemission spectroscopy (ARPES). This observation appears to rule out a direct correlation between the enhanced superconductivity and the tensile strain [5,10].

The electronic structure of the interfaces displaying enhanced $T_c$’s are also remarkably similar across the various substrates. For instance, the Fermi surface measured by ARPES consists of only electron pockets at the corners of the two-Fe Brillouin zone, indicating substantial electron doping from the parent compound. This observation poses a challenge to theories for the high $T_c$ based on the pairing mediated by spin fluctuations that are strongly enhanced by Fermi-surface nesting. One potential solution to this problem is the involvement of bands below the Fermi level in pairing (so-called incipient band pairing) [11–14]. Another possibility is the involvement of a different type of pairing mediator such as nematic fluctuations [15] or phonons particular to the interface [2,4,16]. Evidence for the latter has been provided by the common observation of replica bands in the electronic structure of superconducting FeSe monolayers on SrTiO$_3$ [4,8], BaTiO$_3$ [5], and rutile TiO$_2$ [10].

The replica bands observed by ARPES are exact copies of the original bands crossing the Fermi level in momentum space but with a weaker spectral weight. They are interpreted as being generated by an electron-phonon ($e$-$ph$) interaction between the FeSe electrons and oxygen phonons in the substrate [4,17,18]. This view is supported by the fact that the ~100 meV energy offset between the primary and the replica band coincides with the phonon energy of oxygen modes in SrTiO$_3$ [19], BaTiO$_3$ [20], and TiO$_2$ [10]. Due to the particular properties of the interface [17,21,22], this interaction is strongly peaked for forward scattering (i.e., peaked at small momentum $q$ transfer), as found by analyzing the electrostatic potential from the dipole induced by the oxygen modes [4,17,21] and by first-principles calculations [19,20,22]. This unique momentum structure accounts for the fact that the replicas sharply trace the dispersion of the primary band, which requires that the $e$-$ph$ interactions are forward focused. Such a coupling can also significantly enhance $T_c$, due to the linear dependence of $T_c$ on the dimensionless coupling constant $λ_m$ [18,21], as opposed to the exponential dependence obtained for the usual BCS case. For example, assuming a narrow width $q_0$ for the forward-scattering peak, some of the current authors found $λ_m ∼ 0.15–0.2$ reproduces the measured spectral weight ratio between the replica band and the primary band and at the same time a $T_c ∼ 60–70$ K [18]. Reference [23] has obtained similar results after extending this approach to a more realistic band structure.

Many aspects of the influence of the $e$-$ph$ interactions with strong forward scattering on electronic properties and superconductivity are summarized in Refs. [18,21,24]. In comparison, there are no qualitative or quantitative studies of the phononic properties for the problem at hand. Here, we have carried out such a study to address two issues. First, Zhang et al. [25] recently measured the phonon linewidth of a ~90 meV phonon mode penetrating from the SrTiO$_3$ substrate into thin FeSe films using high-resolution electron-energy-loss spectroscopy (HREELS) and concluded a mode-specific $e$-$ph$...
coupling constant $\lambda \sim 0.25$. Not only does this echo the discovery of replica bands by the ARPES experiments in the same system, but it also calls for a theoretical consideration on the HREELS measurements. Doing so would corroborate both the total coupling strength and momentum dependence of the $e$-$ph$ coupling in FeSe/STO system with those inferred from the ARPES measurements. Second, when a strong $e$-$ph$ coupling is distributed over a subset of wave vectors, one expects tendencies towards charge-density-wave formation that can compete with superconductivity. Such tendencies will manifest themselves as Kohn anomalies in the phonon dispersion and broad phonon linewidths. One can, therefore, address this issue directly by examining the phononic self-energy.

Here, we examine the phonon linewidth due to $e$-$ph$ interactions with strong forward scattering using the same model adopted in Ref. [18] to study the electronic spectral function. We first describe the details of the model and method in Sec. II. Next, in Sec. III we give some analytical results for the normal state phonon properties in the perfect forward-scattering limit, where the interaction is treated as a $\delta$ function at $q = 0$. This limit allows us to derive some analytical results that can guide our thinking. Our numerical results for both the normal and superconducting states with finite $q_0$ are given in Sec. IV. Here, our results show that the forward focused peak in the $e$-$ph$ coupling results in very broad phonon line shapes. However, in Sec. V we reintroduce Coulomb screening, which subsequently endorses the phonon propagator and suppresses these effects. Finally, in Sec. VI we summarize our results and make some concluding remarks in relation to the HREELS experiment of Zhang et al. [25], as well as the replica bands and the superconductivity.

II. MODEL AND METHOD

Our model Hamiltonian describes a single band model of FeSe electrons coupled to an optical phonon branch via a momentum-dependent coupling, which reads

$$H = \sum_{\mathbf{k},\sigma} \xi_{\mathbf{k}} c_{\mathbf{k},\sigma}^\dagger c_{\mathbf{k},\sigma} + \sum_{\mathbf{q}} \omega_{\mathbf{q}} \left( b_{\mathbf{q}}^\dagger b_{\mathbf{q}} + \frac{1}{2} \right)$$

$$+ \frac{1}{\sqrt{N}} \sum_{\mathbf{k},\mathbf{q},\sigma} g(\mathbf{k},\mathbf{q}) c_{\mathbf{k}+\mathbf{q},\mathbf{q},\sigma}^\dagger c_{\mathbf{k},\mathbf{q},\sigma} (b_{\mathbf{q}}^\dagger + b_{\mathbf{q}}). \tag{1}$$

Here, $c_{\mathbf{k},\sigma}^\dagger$ ($c_{\mathbf{k},\sigma}$) creates (annihilates) an electron with wave vector $\mathbf{k}$ and spin $\sigma$, $b_{\mathbf{q}}^\dagger$ ($b_{\mathbf{q}}$) creates (annihilates) a phonon with wave vector $\mathbf{q}$; $\xi_{\mathbf{k}}$ is the electronic band dispersion measured relative to the chemical potential $\mu$; $\omega_{\mathbf{q}}$ is the phonon dispersion ($\hbar = 1$); and $g(\mathbf{k},\mathbf{q})$ is the momentum dependent $e$-$ph$ coupling.

We take a simple electronic band dispersion $\xi_{\mathbf{k}} = -2(\cos(k_xa) + \cos(k_ya)) - \mu$, where $a$ is the in-plane lattice constant. We set $t = 0.075$ eV and $\mu = -0.235$ eV, which produces around the $\Gamma$ point an electronlike Fermi pocket with $k_F = 0.97/a$, a Fermi velocity $v_F = 0.12$ eV $a$/h along the $k_F = 0$ line, and an effective electron band mass $m^*_e \approx (\frac{\hbar^2}{2}\xi_{\mathbf{k}})^{-1} = \frac{\hbar^2}{2\pi^2} = 3.3 m_e$, which is similar to the electron pocket at the $M$ point in FeSe/STO seen in ARPES experiments [4,26,27]. Since we have a single band model, it only takes a trivial $\mathbf{Q} = (\pi/a, \pi/a)$ shift to map our $\Gamma$-point pocket onto the electron pocket in the real system centered at the $M$ point, and any physical quantities depending only on the momentum transfer $\mathbf{q} = \mathbf{k} - \mathbf{k}'$, such as phonon linewidth, do not depend on the position of the pocket. Since we are not considering the effects of an unconventional pairing mechanism here, we do not need to consider the possibility of $d$-wave instabilities due to scattering between the electron pockets. As such, a single band model is sufficient for our purpose.

Throughout we approximate the experimental phonon dispersion with a dispersionless Einstein mode $\omega_{\mathbf{q}} \approx \omega_{\mathbf{ph}} = 100$ meV according to the observed energy separation between the replica band and the primary band [4,10], as well as the phonon dispersion of the interface, as measured by HREELS [25]. We neglect the fermion momentum dependence in the coupling $g(\mathbf{k},\mathbf{q}) = g(\mathbf{q})$, where $\mathbf{q}$ is the momentum transfer and adopt $g(\mathbf{q}) = g_0/8\pi/(a\omega_{\mathbf{q}})^2 \exp(-|q|/q_0)$ as derived from a simple microscopic model [4,17,21]. Here, $g_0$ is adjusted to fix the total dimensionless coupling strength of the interaction and $q_0$ sets the range of the interaction in momentum space. The normalization factor $\sqrt{8\pi/(a\omega_{\mathbf{q}})^2}$ is chosen such that $\langle g^2(q) \rangle \approx g_0^2$ for $q_0 \ll 2\pi$, where $\langle F_{\mathbf{q}}^2 \rangle = a^2 \int_{-\pi/a}^{\pi/a} \int_{-\pi/a}^{\pi/a} d\mathbf{q}d\mathbf{q} \langle \mathbf{q} \rangle / (2\pi)^2$ denotes an momentum integral over the first Brillouin zone. We will typically set the in-plane lattice constant $a = 1$ below; however, we will occasionally write it out for clarity.

In this model, the values of $\omega_{\mathbf{q}}$ and $g(\mathbf{q})$ used in the calculation include all the screening effects within the oxide substrate, but none from the FeSe film. Thus, we refer to them as the “bare” or “unscreened” quantities. In Sec. V, we show that using the unscreened phonon propagator and the unscreened coupling $g(\mathbf{q})$ underestimates the phonon self-energy, especially the imaginary part (phonon linewidth) at $q = 0$, by overlooking the strong screening effect of the FeSe film at small momentum transfers. We also argue that it is justified to approximate the electron self-energy $\Sigma(\mathbf{k},i\nu_n)$ by using the unscreened quantities in the calculation of $\Sigma(\mathbf{k},i\nu_n)$. Such an approximation is useful if one does not carry out a self-consistent calculation. The difference between the fully screened phonon frequency $\omega_{\mathbf{ph}}$ (by both the substrate and the FeSe film) and partially screened $\omega_{\mathbf{q}}$ (only by the substrate itself) is small, however, so we do not distinguish them ($\omega_{\mathbf{q}} \approx \omega_{\mathbf{ph}}$) in Secs. II–IV. Our calculation in Sec. V shows that the difference is within 10% for most parameters. The experimental measurements in Ref. [25] on phonon frequency in SrTiO$_3$ with and without FeSe deposited also support this conclusion.

The electron and phonon self-energies due to $e$-$ph$ interaction are calculated using Migdal-Eliashberg theory, where the vertex part $\Gamma(i\nu_n,\mathbf{k},i\nu_n,\mathbf{q})$ is approximated with the zeroth-order vertex function $g(\mathbf{q})$. Here, $\omega_n$ ($\omega_h$) is the fermionic (bosonic) Matsubara frequency. The relevant diagrams are shown in Fig. 1. As discussed in Ref. [24], in the forward-scattering limit the vertex corrections are of order $\lambda_m$, and can thus be neglected in the weak-coupling regime $\lambda_m \sim 0.15–0.25$ considered here. (In our surface average of the mass enhancement due to the $e$-$ph$ interaction; see Ref. [18].)
This is a reasonable approximation since, on the imaginary
than the screened quantity to calculate the electron self-energy.
Coulomb screening of the
in Sec. V, this treatment is justified when one includes the
approach is the so-called “unrenormalized Migdal-Eliashberg”
imation \([28–30]\) in the nonadiabatic regime for momentum
applies for the forward-focused
electron self-energy  \(\hat{\Sigma}(k, i\omega_n)\) and \(\chi(k, i\omega_n)\) renormalize the single-particle mass and band
dispersion, respectively; and \(\phi(k, i\omega_n)\) is the anomalous self-energy. The electron self-energy is self-consistently
calculated from the one-loop diagram in Fig. 1(a) as follows:
\[
\hat{\Sigma}(k, i\omega_n) = -\frac{1}{N\beta} \sum_{q,v} |g(q)|^2 D_0(q, i\omega_n) \\
\times \hat{\tau}_3 \hat{G}(k - q, i\omega_n - i\omega_v) \hat{\tau}_3,
\]
where \(D_0(q, i\omega_n) = -\frac{2\omega_n}{q^2 + \omega_n^2}\) is the “bare” phonon propagator.
Once we obtain the electron Green’s function self-
consistently, the polarization bubble in Fig. 1(b) is given by
\[
P(q, i\omega_n) = \frac{1}{N\beta} \sum_{k,s} \text{Tr} \left[ \hat{\tau}_3 \hat{G}(k, i\omega_n) \hat{\tau}_3 \right. \\
\left. \times \hat{G}(k - q, i\omega_n - i\omega_v) \right],
\]
and \(\Pi(q, i\omega_n) = |g(q)|^2 P(q, i\omega_n)\) is the phonon self-energy
\(\nu(q, \omega) = -\text{Im} \Pi(q, i\omega_n \to \omega + i\eta)\) is the phonon
linewidth, which has been analytically continued to the real
frequency axis. To perform the analytic continuation we use
the spectral representation of the dressed Green’s function,
\[
\text{Im} \Pi(q, \omega) = -|g(q)|^2 \pi \int_{-\infty}^{\infty} d\omega' \left\{ \nu_{\phi}(\omega' - \omega) - \nu_{\tau}(\omega') \right\} \\
\times \frac{1}{N} \sum_{k} \text{Tr} \left[ \hat{\tau}_3 \hat{A}(k, \omega' - \omega) \hat{\tau}_3 \hat{A}(k + q, \omega') \right],
\]
where \(\nu_{\phi}(x) = 1/(e^{\beta x} + 1)\) is the Fermi-Dirac distribution
function and
\[
\hat{A}(k, \omega) = -\frac{1}{\pi} \text{Im} \hat{G}(k, \omega + i\eta).
\]
\(\hat{G}(k, \omega + i\eta)\) is obtained by the same iterative analytic
continuation method \([33]\) we used in Ref. \([18]\).
Finally, we find the dressed phonon propagator using
\[
D(q, \omega) = \frac{2\omega_{ph}}{\omega^2 - \omega_{ph}^2 + 2i\nu(q, \omega)\omega_{ph}},
\]
and phonon spectral function
\[
B(q, \omega) = -\frac{1}{\pi} \text{Im} D(q, \omega).
\]
In the numerical calculations, we solve the electron self-
energy self-consistently on a 256 \times 256 \(k\) grid. The convergence
for the self-energy is reached if the difference of
the self-energies from two consecutive iterations is less than
10\(^{-3}\) meV. The small imaginary part included in the iterative
analytic continuation is \(\eta = 3\) meV.

III. ANALYTICAL RESULTS FOR THE PERFECT
FORWARD-SCATTERING CASE
We begin by examining the perfect forward-scattering limit,
where several analytical results can be obtained. Here, we
consider only the normal state in the low-temperature limit

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For a normal metal with a parabolic band $\xi_k = \frac{k^2}{2m} - E_F$, i.e., electron gas in three dimensions, the analytical result of Eq. (3) is the Lindhard function [34]. The corresponding result for electron gas in two dimensions is given in Refs. [35,36]. Without the $e$-$\phi$ interaction, we can apply the two-dimensional (2D) electron-gas result to our single band model, due to the small size of the Fermi pocket from the band dispersion $\xi_k = -2t(\cos(k_xa) + \cos(k_ya)) - \mu \approx \frac{k^2}{2m} - E_F$, where $k = |k| = \sqrt{k_x^2 + k_y^2}$, $m^* = \frac{1}{2\pi}$, $E_F = \frac{k_F^2}{2m^*}$, and $k_F = \sqrt{4 + \frac{\mu}{\xi}}$. This approximate band dispersion is exact at the band bottom and suitable for small $k$.

With this approximation, the imaginary part of the electron polarization without $e$-$\phi$ interaction

$$\text{Im} P_0(q,\omega) = -\frac{N_F}{\tilde{q}}[\Theta(1 - v^2)\sqrt{1 - v^2} - \Theta(1 - v^2)\sqrt{1 - v^2}],$$

(8)

where $\tilde{q} = \frac{|q|}{k_F}$, $v_\pm = \omega/(2E_F) \pm \tilde{q}/2$, $N_F = m^*/\pi$ is density of states of two spins, and the step function $\Theta(x) = 1$ for $x > 0$ and $\Theta(x) = 0$ for $x < 0$.

With the inclusion of the $e$-$\phi$ interaction, the self-energy in Eq. (2) is nonzero but diagonal in the normal state. In the perfect forward-scattering limit $|\Omega(q)|^2 = g_0^2(N_0^\phi)(\lambda_m)$, where $g_0 = \sqrt{\pi} / \sqrt{\nu}$, and $\lambda_m \equiv \langle |\Omega(q)|^2 \rangle \approx g_0^2 / \omega^2$. The (1, 1) element of the self-energy is then given by [18]

$$\Sigma(k,\omega_n) = \frac{a\omega^2_0\phi_m}{\omega_n - \xi_k - b\omega_0\phi_m} = \frac{a\omega^2_0\phi_m}{\omega_n - \xi_k - b\omega_0\phi_m},$$

(9)

where $a = \frac{\lambda_m}{\tan \frac{\beta_m}{2}}$ and $b = \frac{\rho_m}{\tan \frac{\beta_m}{2}}$. Using this self-energy and Dyson’s equation, we find that at low temperatures ($T \ll |\xi|$ and $T \ll \omega_{ph}$), the dressed Green’s function acquires a two-pole form,

$$G(k,\omega_n) = \frac{A_M}{\omega_n - \xi_k^M} + \frac{A_R}{\omega_n - \xi_k^R},$$

(10)

where $A_{M,R} = (\sqrt{1 + 4\lambda_m} \pm 1)/(2\sqrt{1 + 4\lambda_m})$ and $\xi_k^{M,R} = \xi_k \pm \frac{1}{2} \text{sgn}(\xi_k)\omega_{ph}(1 \mp \sqrt{1 + 4\lambda_m})$. Here, “M” and “R” denote the main and replica band, respectively. To simplify the calculation, we shift the two bands by the same energy $-\frac{1}{2} \text{sgn}(\xi_k)\omega_{ph}(1 - \sqrt{1 + 4\lambda_m})$ (which is small if $\lambda_m \ll 1$), and the dressed Green’s function becomes

$$G(k,\omega_n) = \frac{A_M}{\omega_n - \xi_k^R} + \frac{A_R}{\omega_n - \xi_k^R},$$

(11)

where the shifted $\xi_k^R = \xi_k + \text{sgn}(\xi_k)\Delta\omega$ and $\Delta\omega = \omega_{ph}\sqrt{1 + 4\lambda_m}$. Here, $A_M + A_R = 1$. Physically, Eq. (11) clearly indicates that the replica band exactly follows the dispersion of the main band, and its energy offset from the main band is $+\Delta\omega$ ($-\Delta\omega$) for the part of the main band above (below) the Fermi level.

Using Eq. (11), the imaginary part of the electron polarization with the $e$-$\phi$ interaction in the perfect forward-scattering limit can be expressed in terms of the noninteracting electron polarization as follows:

$$\text{Im} P(q,\omega) = A_M^2 \text{Im} P_0(q,\omega) + 2A_M A_R \text{Im} P_0(q,\omega - \text{sgn}(\omega)\Delta\omega)\Theta(|\omega| - \Delta\omega) + A_R^2 \text{Im} P_0(q,\omega - \text{sgn}(\omega)2\Delta\omega)\Theta(|\omega| - 2\Delta\omega).$$

(12)

Here, $\text{sgn}(\omega)$ is the sign of $\omega$. Equation (12) is also a good approximation when the coupling function $g(q) \propto \exp(-|q|/\rho_0)$ has a sharp peak $(\rho_0 \ll \pi/a)$. Then, the phonon linewidth is given by $\gamma(q,\omega) = -g(q)^2 \text{Im} P(q,\omega)$.

In Fig. 2 we show $-\text{Im} P(q,\omega)$ calculated from Eq. (8) and from Eq. (12) in panel (a) and (b), respectively. Figure 2(a) manifests the electron-hole continuum for 2D electron gas at low temperature, while Fig. 2(b) shows multiple-scattering processes at low temperature corresponding to the three terms in Eq. (12); one within the main band for $|\omega| > \omega_{ph}$ that represents the original electron-hole continuum, one between the main and replica band for $|\omega| > \Delta\omega = \omega_{ph}\sqrt{1 + 4\lambda_m}$, and one within the replica band for $|\omega| > 2\Delta\omega$, in a descending order of weights ($A_{M}^2$, $2A_M A_R$, and $A_R^2$). As shown in Fig. 2(b), at the fixed frequency $\omega = \omega_{ph}$, the magnitude of the imaginary part of the electron polarization has a sharp upturn at a finite momentum, leading to a peak that slowly decreases.
The double Fermi-surface averaged coupling constant (defined in the ω imaginary part of the electron polarization in momentum space. Figure 3 shows the imaginary part of the coupling constant is a full numerical result in the next section. Note that since the at larger momentum. This qualitative feature persists in the full numerical result in the next section. Note that since the coupling constant is a δ function, the phonon linewidth γ(q,ω) is zero at all q values despite the fact that the polarization P(q,ω) is nonzero.

IV. NUMERICAL RESULTS

We now turn to the polarization and phonon linewidth for the case of an e–ph interaction with a small but nonzero width in momentum space. Figure 3 shows the imaginary part of the electron polarization − Im P(q,ω) and the phonon linewidth γq = − Im Π(q,ω) for various temperatures. Here, we have parametrized the total e–ph coupling using the double Fermi-surface averaged definition

\[ \lambda = \frac{2}{\omega_{ph} N_F N^2} \sum_{k,k'} |g(k - k')|^2 \delta(\xi_k) \delta(\xi_{k'}) \]  

where \( N_F \) is the density of states per spin and \( N^2 - \sum_{k,k'} \delta(\xi_k) \delta(\xi_{k'}) = N_F^2 \). We have used this definition because the q-averaged \( \lambda_m = \langle |g(q)|^2 \rangle / \omega_{ph}^2 = \lambda_0^2 / \omega_{ph}^2 \) equals the mass enhancement factor − Re \( \sum_{k,k'} \lambda_0 \delta(\xi_k) \delta(\xi_{k'}) \) only in the limit of perfect forward scattering, while \( \lambda \) approximates the mass enhancement factor when the e–ph interaction is more uniform. The latter case occurs for the larger values of \( q_0 \) used in Fig. 3. In addition, \( \lambda \) as defined in Eq. (13) does not depend on temperature whereas \( \lambda_0 \) does. Empirically, we find \( \lambda_m \propto (q_{ph})^2 \lambda \) (see Ref. [24] for the proportionality constant), which can be used to approximate convert between the two definitions. In Fig. 3 we have set \( \lambda = 0.8 \), which is equivalent to \( \lambda_m = 0.16 \) for \( q_0 = 0.1/a \) and within the suitable range of values that simultaneously fit both the high \( T_c \) value and the measured spectral weight of the replica bands [18].

At low temperature and \( \omega = \omega_{ph} \), the imaginary part of the polarization in Fig. 3(a) has a peak appearing at \( |q| = \sqrt{2m^* \omega_{ph}} \), which is a feature of the electron-hole continuum; with increasing temperature, the − Im \( P(q = 0, \omega_{ph}) \) increases, and the rate of increase is faster for smaller values of \( q_0 \). The phonon linewidth, shown in Fig. 3(b), strongly peaks at \( q = 0 \) for \( q_0 = 0.1 \) because the forward-scattering coupling \( g(q) \) strongly suppresses the peak in the polarizability appearing at the finite \( |q| \). As the value of \( q_0 \) increases, however, the width of \( g(q) \) begins to overlap with the peak in the polarization, and a corresponding peak in the linewidth recovers at nonzero \( q \). In this case, both the temperature and the width of the coupling function \( g(q) \) dictate the full \( q \) dependence of the phonon linewidth. Thus, due to its sensitivity to these parameters, the momentum dependence of the phonon linewidth can be used to determine not only the overall strength of the e–ph interaction but also the width of the coupling function.

To reproduce the replica bands observed in the ARPES experiments, the width of the e–ph coupling must be narrow in momentum space with \( q_0 \approx 0.1/a – 0.5/a \). Based on this observation, and the results shown in Fig. 3, one might expect that the phonon linewidth in the vicinity of \( q = 0 \) should be very large. In turn, the real part of the phonon self-energy will also develop significant Kohn anomaly, leading to an instability of the lattice. It turns out that the Coulomb interaction will prevent this from occurring, as the divergence in the Coulomb interaction at \( q = 0 \) effectively blocks the long-wavelength instability. We will discuss this issue in the next section.

V. UNDRESSING OF THE PHONON LINEWIDTH DUE TO COULOMBIC SCREENING

In this section we examine the effects of Coulomb screening by the FeSe electrons on the e–ph vertex and the phonon linewidth. Figure 1(c) shows the diagrammatic expansion of the screened e–ph vertex evaluated at the level of the random-phase approximation. The screened vertex is

\[ \tilde{g}(q,i\omega_n) = g(q) + g(q)[-V_c(q)\chi_0(q,i\omega_n)] \]

\[ + g(q)[-V_c(q)\chi_0(q,i\omega_n)]^2 + \cdots \]

\[ = \frac{g(q)}{1 + V_c(q)\chi_0(q,i\omega_n)}. \]

where \( \chi_0(q,i\omega_n) = -P(q,i\omega_n) \) is the charge susceptibility and \( V_c(q) \) is the Fourier transform of the Coulomb potential. In the continuum limit, \( V_c(q) = 4\pi e^2 / q^2 \) in three dimensions and \( V_c(q) = 2\pi e^2 / q \) in two dimensions. The corresponding phonon self-energy is obtained by replacing the vertex function with
the screened vertex with

$$\Pi(q, i\omega_n) = g(q)[\tilde{g}(q, i\omega_n)]^*\left[-\chi_0(q, i\omega_n)\right]$$

$$= -|g(q)|^2\chi_0(q, i\omega_n) / \left[1 + V_C(q)\chi_0(q, i\omega_n)\right],$$

(15)

where we have assumed $V_C(q)\chi_0(q, i\omega_n)$ is real.

Here, we are interested in the case of an FeSe monolayer located a distance $h$ above the oxide substrate. We place the FeSe electrons at $z = 0$ and the ions in the termination layer of the substrate at $z = -h$. For this geometry, we introduce an anisotropic Coulomb potential $[37]$

$$V_C(q, q_z) = \frac{4\pi e^2}{\epsilon_a q^2 + \epsilon_c q_z^2},$$

(16)

where $q = \sqrt{q_x^2 + q_y^2}$ is the momentum transfer in a plane parallel to the FeSe monolayer, and $\epsilon_a$ and $\epsilon_c$ are the zero-frequency dielectric constants parallel and perpendicular to the plane. By inverse Fourier transform, the real-space formula is

$$V_C(x, y, z) = \frac{e^2}{\sqrt{\epsilon_a\epsilon_c}} \frac{1}{\sqrt{r^2 + z^2}},$$

(17)

where $r^2 = x^2 + y^2$ and $\tilde{z} = (\epsilon_a/\epsilon_c)z^2$. After performing the 2D Fourier transform for the in-plane coordinates we arrive at

$$V_C(q, z) = \frac{2\pi e^2}{\sqrt{\epsilon_a\epsilon_c}} \frac{e^{-|q|z}}{q},$$

(18)

To compute the screened $e$-ph interaction, we must use the interaction at $z = 0$ for the Coulomb potential since the particle-hole pairs are created in the FeSe layer. Putting this all together, the phonon linewidth is given by

$$\gamma(q, \omega) = \frac{\omega_{\text{ph}}}{\omega_{\text{ph}}} \text{Im} \frac{|g(q)|^2\chi_0(q, \omega)}{1 + V_C(q, z = 0)\chi_0(q, \omega)/q^2},$$

(19)

where we define the “unscreened” phonon energy as $\omega_{\text{ph}} = \sqrt{\omega_{\text{ph}}^2 + [\text{Re} \Pi(q, \omega)]^2 - \text{Re} \Pi(q, \omega)}$.

We evaluated Eq. (19) for several values of $q_0$ and $\lambda$, and the results are shown in Fig. 4. Since the exact values of the dielectric constants are not known for the FeSe interface systems, we show results for $\epsilon_a = \epsilon_c = 1$ in Fig. 4(a) and $\epsilon_a = 25, \epsilon_c = 1$ in Fig. 4(b). Note that the latter values are close to the estimates obtained by Kulic and Dolgov (Ref. [21]) in the limit of perfect forward scattering. In both cases, we find that the phonon linewidth is dramatically suppressed once Coulomb screening is included; however, as the values of $\epsilon_a$ and $\epsilon_c$ are increased, the magnitude of the linewidth increases. These results indicate that the long-range Coulomb interaction can prevent the formation of a competing charge ordering at long wavelengths, which is consistent with the notion that extended Coulomb interactions can suppress insulating behavior [38]. Our results also show that this effect will be somewhat sensitive to the dielectric properties of the interface, which may offer a means to tune these properties. Finally, the undressing of the phonon linewidth observed here also provides a rationale for adopting an unrenormalized Migdal-Eliashberg scheme, where the phonon self-energy is not fed back into the electron self-energy in a self-consistent manner. In this case, the calculated phonon self-energy is small, justifying the use of the bare phonon propagator in the electron self-energy diagrams.

Comparing our results to the recent RHEELS measurements by Zhang et al. [25], we find that once the Coulomb screening is included, the computed linewidths are much smaller than those inferred experimentally. Moreover, in the experimental data, the linewidth is finite at the $\Gamma$ point and maximal around the $X$ point. Our calculated linewidth is exactly zero at the $\Gamma$ point because the screening from the Coulomb potential diverges at $q = 0$. However, we have not considered any impurity potential in our calculation, or other sources of broadening in the electron Green’s function, and, subsequently, the phonon linewidth once the charge susceptibility $\chi_0$ is computed. Regardless, the $X$ point is not the maximal point for the linewidth in any of our calculation results. This discrepancy could also be due to the limitation of our single band model. The real system is multiband in nature and also shows strong magnetic fluctuations.

VI. SUMMARY AND CONCLUSIONS

In this paper, we have calculated the phonon linewidth, i.e., the imaginary part of the phonon self-energy in an unrenormalized Migdal-Eliashberg scheme in the weak to intermediate coupling regime for strong forward-scattering $e$-ph interaction. Such an $e$-ph interaction dresses the electron propagator by simply creating the replica bands and shuffles the electron-hole continuum of 2D electron gas into three similar parts with descending weights beginning at $|\omega| > 0$, $|\omega| > \Delta\omega$, and $|\omega| > 2\Delta\omega$. If we do not include Coulomb screening, the phonon linewidth is a simple product
of coupling function $|g(q)|^2$ with a forward-scattering peak around $q = 0$ and the electron polarization with a very similar momentum structure of the electron-hole continuum of the 2D electron gas. Depending on the peak width $q_0$ of the e-ph coupling constant $g(q)$ and the peak of electron polarization at $|q| = \sqrt{2m^{*}\omega_{ph}}$, we find the linewidth $\gamma(q,\omega_{ph})$ has a maximum value at $q = 0$ or $|q| \approx \sqrt{2m^{*}\omega_{ph}}$ at low temperature, and the linewidth is broad at $q = 0$. Even if the latter happens, since the linewidth for small $|q|$ tends to increase with temperature, the maximum may shift back to $q = 0$ at high temperature. The momentum resolved phonon spectral function at $\omega \approx \omega_{ph}$ can be understood in the same picture.

The broad linewidths at $q = 0$ would normally indicate an instability to a charge-ordered phase at long wavelengths. However, once the long-range Coulomb interaction screens the e-ph interaction we find that the phonons are undressed. Here, the anomalous broadening at $q = 0$ is suppressed by the divergence in the Coulomb interaction at $q = 0$ while the total phonon linewidth is reduced throughout the Brillouin zone. In this case, a small peak remains at nonzero momentum transfers; however, the magnitude of this peak is much smaller than the linewidths measured by HREELS [25]. Our results provide one possible rationale for why anomalously broad line shapes are not observed in the FeSe/STO system in the presence of the forward-focused e-ph interaction. They also suggest that the broadening of the SrTiO$_3$ phonons (with a maximum at $X$ point) observed by Zhang et al. are not due to the forward-focused e-ph coupling inferred from the ARPES measurements. To resolve the forward-focused e-ph interaction, the HREELS experiments should focus on smaller values of $q$, which will be challenging given the large background signal at $q = 0$. The observed linewidths may also be the result of some other source of broadening, or they might mean that the e-ph interaction is broader in momentum space than is implied by the ARPES measurements. Further work is needed to address these possibilities.

Finally, we note that a fully self-consistent calculation of the phononic and electronic properties would require the use of the screened e-ph vertex into the expression for the electron self-energy. However, since the phonons are essentially undressed, and at nonzero frequencies the coupling vertex (on the imaginary axis) is nearly unscreened for small $q$ (the screening effect from electron-hole pairs with a small total momentum $q$ but a large frequency is rather weak), we expect that the conclusions reached previously on the replica band feature and enhanced $T_c$ will be essentially unchanged, although $T_c$ will be reduced by the elimination of the static term due to the screening effect. A more rigorous check of this claim will be carried out in future work.

Note added. Recently, the eprint [39] of a calculation on the same topic was available on the arXiv server.

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